

## **SPICE Device Model Si7636DP Vishay Siliconix**

### N-Channel 30-V (D-S) MOSFET

#### **CHARACTERISTICS**

- N-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS

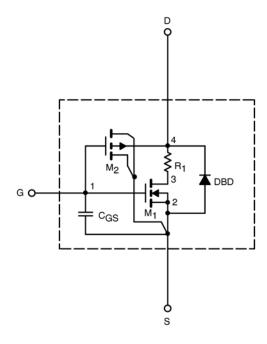
- · Apply for both Linear and Switching Application
- Accurate over the -55 to 125°C Temperature Range
- · Model the Gate Charge, Transient, and Diode Reverse Recovery Characteristics

#### **DESCRIPTION**

The attached spice model describes the typical electrical characteristics of the n-channel vertical DMOS. The subcircuit model is extracted and optimized over the -55 to 125°C temperature ranges under the pulsed 0-V to 10-V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched  $C_{\text{gd}}$  model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

#### SUBCIRCUIT MODEL SCHEMATIC



This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

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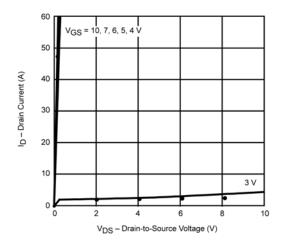
SPECIFICATIONS (T <sub>J</sub> = 25°C UNLESS OTHERWISE NOTED)					
Parameter	Symbol	Test Condition	Simulated Data	Measured Data	Unit
Static			-		•
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1.9		V
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS}~\geq 5~V,~V_{GS}$ = 10 $V$	1882		Α
Drain-Source On-State Resistance <sup>a</sup>	r <sub>DS(on)</sub>	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 25 A	0.0033	0.0033	Ω
		$V_{GS} = 4.5 \text{ V}, I_D = 19 \text{ A}$	0.0040	0.0040	
Forward Transconductance <sup>a</sup>	g <sub>fs</sub>	$V_{DS}$ = 15 V, $I_{D}$ = 25 A	95	110	S
Forward Voltage <sup>a</sup>	V <sub>SD</sub>	$I_S = 2.9 \text{ A}, V_{GS} = 0 \text{ V}$	0.83	0.72	V
Dynamic <sup>b</sup>			-		-
Total Gate Charge	$Q_g$	$V_{DS}$ = 15 V, $V_{GS}$ = 4.5 V, $I_{D}$ = 20 A	37	32	nC
Gate-Source Charge	$Q_{gs}$		16.5	16.5	
Gate-Drain Charge	$Q_{gd}$		8.5	8.5	
Turn-On Delay Time	t <sub>d(on)</sub>	$V_{DD}$ = 15 V, $R_L$ = 15 $\Omega$ $I_D \cong 1 \text{ A, } V_{GEN}$ = 10 V, $R_G$ = 6 $\Omega$	22	24	ns
Rise Time	t <sub>r</sub>		13	16	
Turn-Off Delay Time	t <sub>d(off)</sub>		70	90	
Fall Time	$t_f$		55	32	

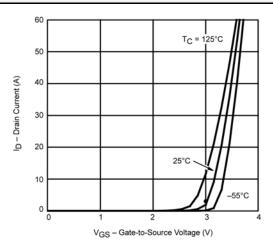
- Notes a. Pulse test; pulse width  $\leq$  300  $\mu s,$  duty cycle  $\leq$  2%. b. Guaranteed by design, not subject to production testing.

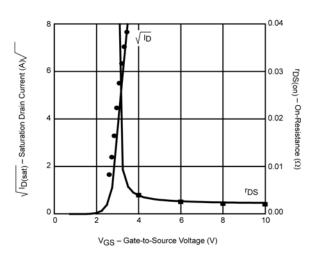


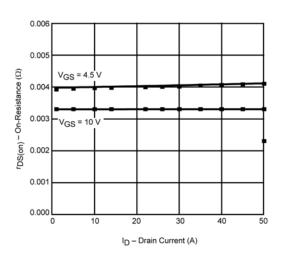
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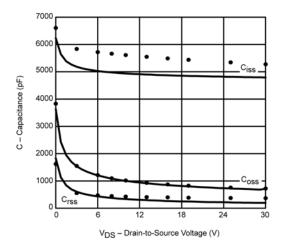
### COMPARISON OF MODEL WITH MEASURED DATA (TJ=25°C UNLESS OTHERWISE NOTED)

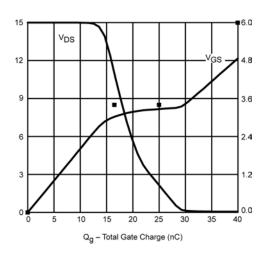












Note: Dots and squares represent measured data.



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